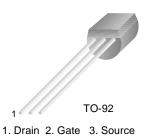


SEMICONDUCTOR®

# 2N3819

## **N-Channel RF Amplifier**

- This device is designed for RF amplifier and mixer applications operating up to 450MHz, and for analog switching requiring low capacitance.
- Sourced from process 50.



# **Epitaxial Silicon Transistor**

## Absolute Maximum Ratings\* $T_C=25^{\circ}C$ unless otherwise noted

| Symbol           | Parameter                 | Ratings   | Units |
|------------------|---------------------------|-----------|-------|
| V <sub>DG</sub>  | Drain-Gate Voltage        | 25        | V     |
| V <sub>GS</sub>  | Gate-Source Voltage       | -25       | V     |
| D                | Drain Current             | 50        | mA    |
| GF               | Forward Gate Current      | 10        | mA    |
| T <sub>STG</sub> | Storage Temperature Range | -55 ~ 150 | °C    |

\* This ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

These rating are based on a maximum junction temperature of 150 degrees C.
These are steady limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

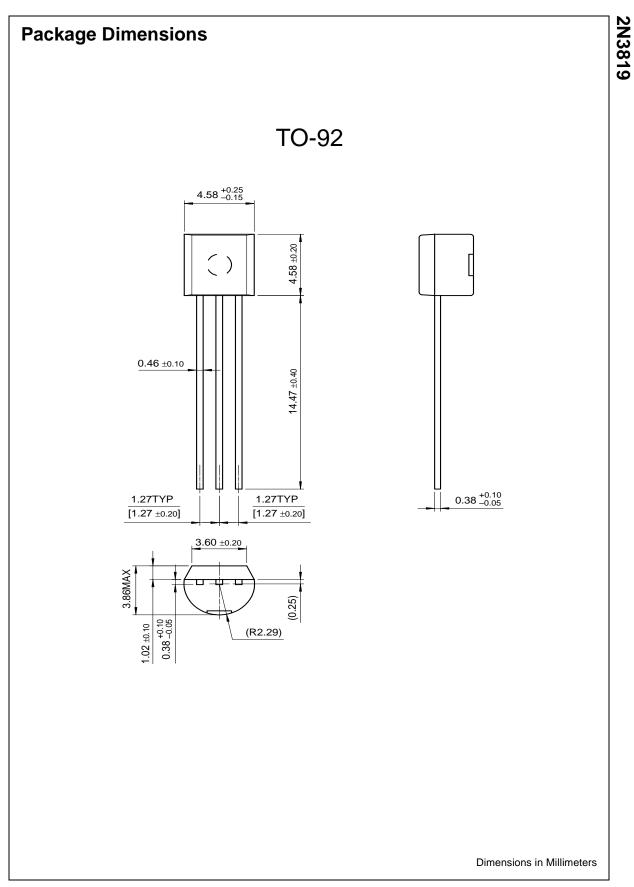
### Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

| Symbol                | Parameter                       | Test Condition   | Min. | Тур. | Max. | Units |
|-----------------------|---------------------------------|--|------|------|------|-------|
| Off Charac            | teristics                       | •  |      |      | •    | •     |
| V <sub>(BR)GSS</sub>  | Gate-Source Breakdwon Voltage   | $I_{G} = 1.0 \mu A, V_{DS} = 0$                        | 25   |      |      | V     |
| I <sub>GSS</sub>      | Gate Reverse Current            | $V_{GS} = -15V, V_{DS} = 0$                            |      |      | 2.0  | nA    |
| V <sub>GS</sub> (off) | Gate-Source Cutoff Voltage      | $V_{DS} = 15V, I_{D} = 2.0nA$                          |      |      | 8.0  | V     |
| V <sub>GS</sub>       | Gate-Source Voltage             | $V_{DS} = 15V, I_{D} = 200\mu A$                       | -0.5 |      | -7.5 | V     |
| On Charac             | teristics                       |  |      |      | •    |       |
| I <sub>DSS</sub>      | Zero-Gate Voltage Drain Current | $V_{DS} = 15V, V_{GS} = 0$                             | 2.0  |      | 20   | mA    |
| Small Sign            | al Characteristics              |  |      |      | •    |       |
| gfs                   | Forward Transfer Conductance    | $V_{DS} = 15V, V_{GS} = 0, f = 1.0KHz$                 | 2000 |      | 6500 | μmhos |
| goss                  | Output Conductance              | V <sub>DS</sub> = 15V, V <sub>GS</sub> = 0, f = 1.0KHz |      |      | 50   | μmhos |
| y <sub>fs</sub>       | Forward Transfer Admittance     | V <sub>DS</sub> = 15V, V <sub>GS</sub> = 0, f = 1.0KHz | 1600 |      |      | μmhos |
| C <sub>iss</sub>      | Input Capacitance               | V <sub>DS</sub> = 15V, V <sub>GS</sub> = 0, f = 1.0KHz |      |      | 8.0  | pF    |
| C <sub>rss</sub>      | Reverse Transfer Capacitance    | V <sub>DS</sub> = 15V, V <sub>GS</sub> = 0, f = 1.0KHz |      |      | 4.0  | pF    |

# Thermal Characteristics $T_A=25^{\circ}C$ unless otherwise noted

| Symbol   | Parameter                               | Max. | Units |  |
|--|---|------|-------|--|
| PD   | Total Device Dissipation                | 350  | mW    |  |
|  | Derate above 25°C                       | 2.8  | mW/°C |  |
| $R_{\theta JC}$                                  | Thermal Resistance, Junction to Case    | 125  | °C/W  |  |
| $R_{\theta JA}$                                  | Thermal Resistance, Junction to Ambient | 357  | °C/W  |  |
| * Device mounted on FR-4 PCB 1.5" × 1.6" × 0.06" |   |      |       |  |

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### **PRODUCT STATUS DEFINITIONS**

#### **Definition of Terms**

| Datasheet Identification | Product Status            | Definition  |
|--------------------------|---------------------------|---|
| Advance Information      | Formative or In<br>Design | This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.  |
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| No Identification Needed | Full Production           | This datasheet contains final specifications. Fairchild<br>Semiconductor reserves the right to make changes at<br>any time without notice in order to improve design.   |
| Obsolete                 | Not In Production         | This datasheet contains specifications on a product<br>that has been discontinued by Fairchild semiconductor.<br>The datasheet is printed for reference information only.   |